## **SEMICONDUCTOR**

TECHNICAL DATA DATA SHEET 516, REV. A

# SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop 200°C Operating Temperature

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging
- Out Performs 100 Volt Ultrafast Rectifiers

## **Maximum Ratings:**

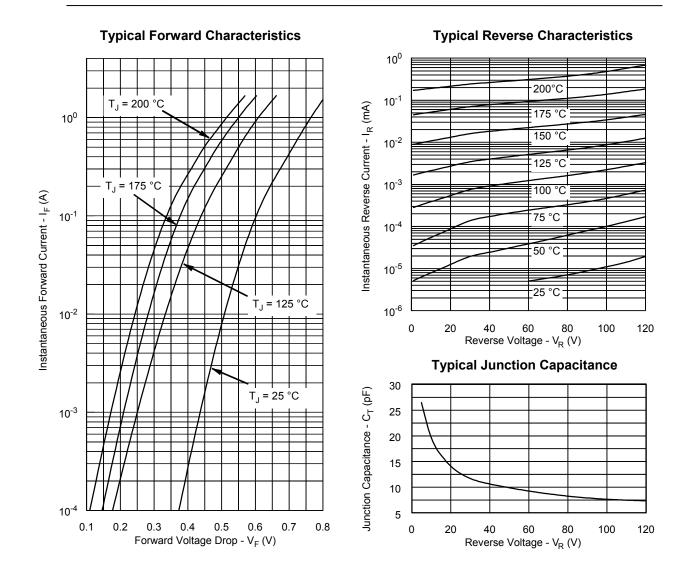
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form	1	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave (1)	20	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.13 \text{A}, \\ L = 227\text{mH}$	2.0	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 $\mu$ s $f$ limited by $T_J$ max $V_A$ =1.5 $V_R$	0.13	Α
Max. Junction Temperature	$T_J$	-	-65 to +200	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +200	°C

## **Electrical Characteristics:**

Characteristics	<b>Symbol</b>	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 1A, Pulse, T <sub>J</sub> = 25 °C	0.84	V
	$V_{F2}$	@ 1A, Pulse, T <sub>J</sub> = 125 °C	0.68	V
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 100V, Pulse,	30	μΑ
		T <sub>J</sub> = 25 °C		
	$I_{R2}$	@V <sub>R</sub> = 100V, Pulse,	0.6	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	$C_T$	$@V_R = 5V, T_C = 25  ^{\circ}C$	35	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

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#### **SENSITRON**

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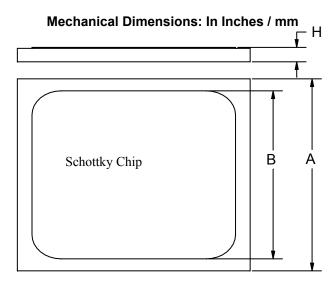


Figure 1

A	В	Н
$0.040\pm0.003$	$0.034\pm0.003$	0.0105±0.001 (Al Top)
		0.0155±0.001 (Ag Top)

Top side(Anode) metallization:

A = A1 - 25 kÅ minimum, Figure 1

B = Ag - 30 kÅ minimum, Figure 1

Bottom side (Cathode) metallization: A, B = Ti/Ni/Ag - 30 kÅ minimum.

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